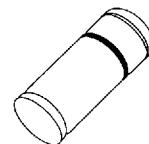


TEMPERATURE COMPENSATED ZENER DIODES

NEW SERIE


 MINIMELF
 (Glass)

ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		Value	Unit
P _{tot}	Power Dissipation	T _{leads} = 50°C	0.4	W
T _{stg} T _J	Storage and Junction Temperature Range		- 65 to 175 - 55 to 175	°C °C
T _L	Maximum Temperature for Soldering during 15s		260	°C

THERMAL RESISTANCE

Symbol	Parameter		Value	Unit
R _{th(j-l)}	Junction-leads		300	°C/W

 ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C unless otherwise specified)

Types	V _{ZT} typ. (V)	R _{ZT} @ I _{ZT} max. (Ω)	I _{ZT} (mA)	Test Temperatures					ΔV _Z * max. (mV)	αV _Z (10 ⁻⁶ /°C)
				(°C)						
TMM821	6.2	15	7.5	- 55	0	+ 25	+ 75	+ 100	96	100
TMM823	6.2	15	7.5	- 55	0	+ 25	+ 75	+ 100	48	50
TMM825	6.2	15	7.5	- 55	0	+ 25	+ 75	+ 100	19	20
TMM827	6.2	15	7.5	- 55	0	+ 25	+ 75	+ 100	9	10
TMM829	6.2	15	7.5	- 55	0	+ 25	+ 75	+ 100	5	5
TMM821A	6.2	10	7.5	- 55	0	+ 25	+ 75	+ 100	96	100
TMM823A	6.2	10	7.5	- 55	0	+ 25	+ 75	+ 100	48	50
TMM825A	6.2	10	7.5	- 55	0	+ 25	+ 75	+ 100	19	20
TMM827A	6.2	10	7.5	- 55	0	+ 25	+ 75	+ 100	9	10
TMM829A	6.2	10	7.5	- 55	0	+ 25	+ 75	+ 100	5	5

* The voltage reference diodes are characterized by the box method. The maximum allowable voltage change ΔV_Z is guaranteed any two temperature within the range. Tests are performed at the indicated temperatures and the specified current.

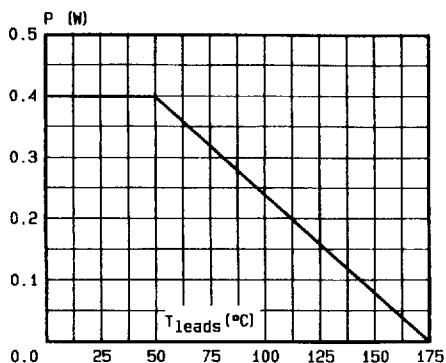


Fig.1 - Power dissipation versus leads temperature.

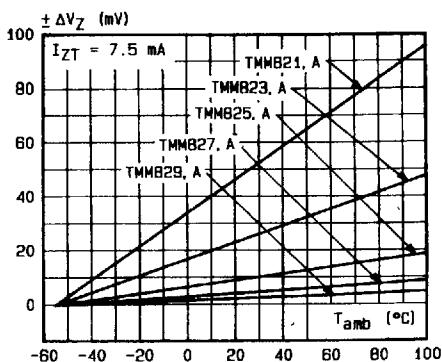
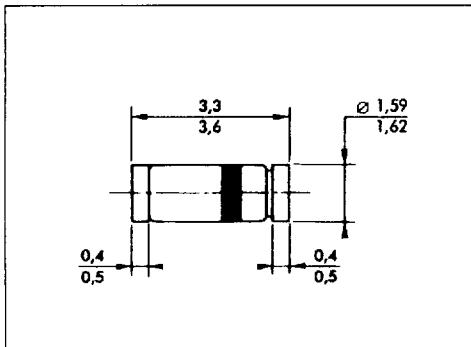


Fig.2 - Regulation voltage variation versus ambient temperature.

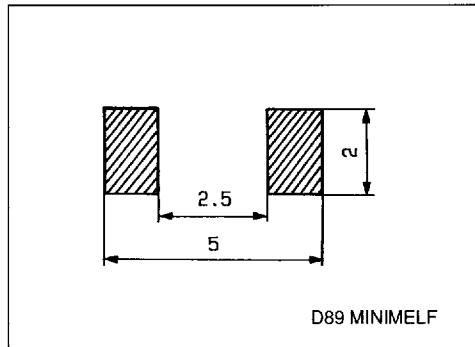
PACKAGE MECHANICAL DATA

MINIMELF Glass



Marking clear, ring at cathode end
Weight 0.05g

FOOT PRINT DIMENSIONS (Millimeter)



D89 MINIMELF